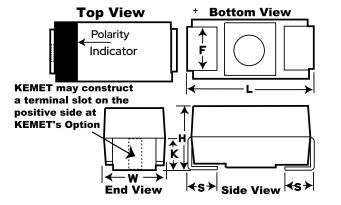


T510X337K010ZTE0357280 Obsolete B45396R. Tantalum. MnO2 Tantalum. Multi-Anode, 330 uF. 1

B45396R, Tantalum, MnO2 Tantalum, Multi-Anode, 330 uF, 10%, 10 VDC, SMD, Molded, Ultra Low ESR, 35 mOhms, 7343, 4.4 mm, 1.3 mm



Packaging Specifications	
Packaging	T&R, 330mm
Packaging Quantity	1800

General Information	
Series	B45396R
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, Molded, Ultra Low ESR
Features	Ultra Low ESR
RoHS	Yes
Termination	Tin
AEC-Q200	No

Specifications	
Capacitance	330 uF
Tolerance	10%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
ESR	0.035 Ohms (100kHz)
Ripple Current	2800 mAmps (25C), 2520 mAmps (85C), 1120 mAmps (125C)
Leakage Current	33 uA

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